INFN/0037 10/720,730 ATTY. DKT. No.: U.S. SERIAL NO.:

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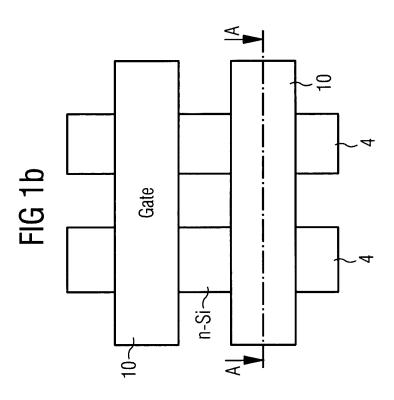
INVENTOR: REPLACEMENT DRAWINGS

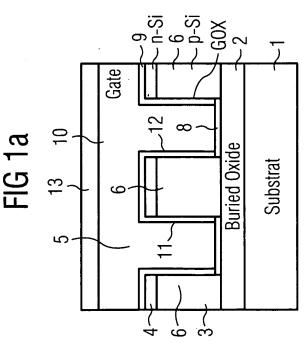
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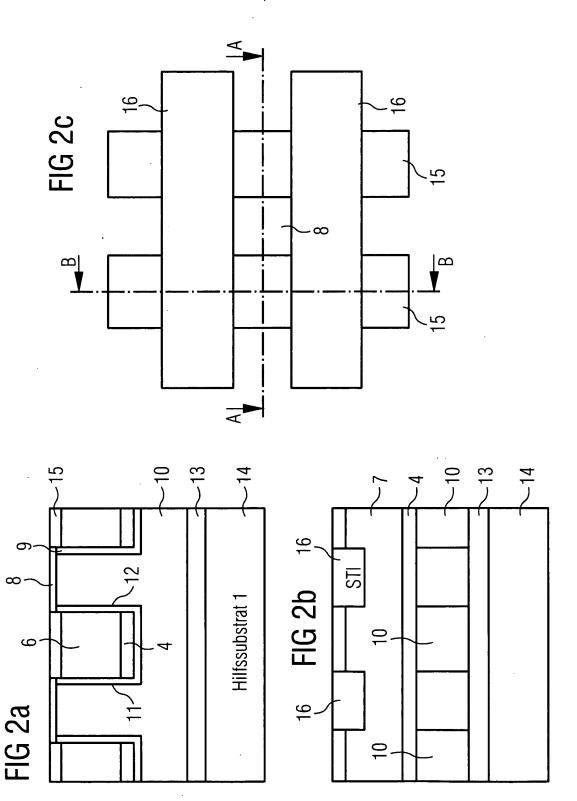
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DRAM CELL ARRANGEMENT WTH VERTICAL MOS
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